

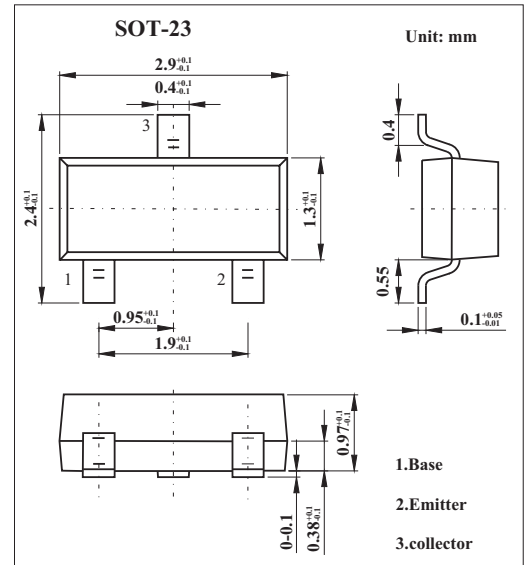
SOT-23 Plastic-Encapsulate Transistors

Features

- Low collector to emitter saturation voltage $V_{CE(sat)}$.
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing.

MECHANICAL DATA

- Case style: SOT-23 molded plastic
- Mounting position: any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	30	V
Collector-emitter voltage	V_{CEO}	25	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_C	500	mA
Peak collector current	I_{CP}	1	A
Collector power dissipation	P_C	200	mW
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

PACKAGE INFORMATION

Device	Package	Shipping
2SD602	SOT-23	3000/Tape&Reel

Parameter	Symbol	Testconditions	Min	Typ	Max	Unit
Collector-base voltage	V_{CBO}	$I_C = 10 \mu A, I_E = 0$	30			V
Collector-emitter voltage	V_{CEO}	$I_C = 10 mA, I_B = 0$	25			V
Emitter-base voltage	V_{EBO}	$I_E = 10 \mu A, I_C = 0$	5			V
Collector-base cutoff current	I_{CBO}	$V_{CB} = 20 V, I_E = 0$			0.1	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = 10 V, I_C = 150 mA$	85	160	340	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 300 mA, I_B = 30 mA$		0.35	0.6	V
Transition frequency	f_T	$V_{CB} = 10 V, I_E = -50 mA, f = 200 MHz$		200		MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10 V, I_E = 0, f = 1.0 MHz$		6	15	pF

hFE Classification

Marking	WQ1	WR1	WS1
hFE	85~170	120~240	170~340